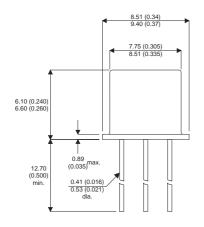
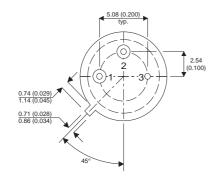




#### **MECHANICAL DATA**

Dimensions in mm (inches)





### **TO39 PACKAGE**

#### **Underside View**

Pin 1 = Emitter Pin 2 = Base Pin 3 = Collector

### **NPN SILICON TRANSISTOR**

## **FEATURES**

- NPN High Voltage Planar Transistor
- Hermetic TO39 Package
- Full Screening Options Available

# **ABSOLUTE MAXIMUM RATINGS** (T<sub>case</sub> = 25°C unless otherwise stated)

$V_{CBO}$	Collector – Base Voltage	150V
$V_{CEO}$	Collector – Emitter Voltage (I <sub>B</sub> = 0)	150V
$V_{EBO}$	Emitter – Base Voltage (I <sub>B</sub> = 0)	6V
I <sub>C</sub>	Collector Current	300mA
$P_{D}$	Total Device Dissipation T <sub>A</sub> = 25 °C	1W
$P_{D}$	Derate above 25°C	5.71mW / °C
$T_{stg}$	Storage Temperature	–65 to 200°C
R <sub>ja</sub>	Thermal Resistance Junction to Ambient	175°C/W

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

E-mail: sales@semelab.co.uk

**Semelab plc.** Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

Website: http://www.semelab.co.uk





### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
	OFF CHARACTERISTICS	•				ı	1
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage <sup>1</sup>	I <sub>C</sub> = 10mA	I <sub>B</sub> = 0	150			
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 10\mu A$	I <sub>E</sub> = 0	150			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 10μA	I <sub>C</sub> = 0	6			
(=: -)===		V <sub>CB</sub> = 75V	I <sub>E</sub> = 0			0.05	
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 75V	I <sub>E</sub> = 0			50	μΑ
			T <sub>A</sub> = 150°C			50	
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB(off)} = 4V$	I <sub>C</sub> = 0			25	nA
	ON CHARACTERISTICS	•		1		I	ı
		$I_C = 0.1 \text{mA}$	V <sub>CE</sub> = 10V	35			
		I <sub>C</sub> = 1mA	V <sub>CE</sub> = 10V	50			
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 10mA	$V_{CE} = 10V^{1}$	75			_
		I <sub>C</sub> = 150mA	$V_{CE} = 10V^{1}$	100		300	1
		$I_C = 300 \text{mA}$	$V_{CE} = 10V^{1}$	20			
	Collector-Emitter Saturation Voltage <sup>1</sup>	$I_C = 10mA$	I <sub>B</sub> = 1mA			0.2	V
V <sub>CE(SAT)</sub>		I <sub>C</sub> = 50mA	I <sub>B</sub> = 5mA			0.25	
- (- )		I <sub>C</sub> = 150mA	I <sub>B</sub> = 15mA			0.4	
V <sub>BE(SAT)</sub>	Base-Emitter Saturation Voltage <sup>1</sup>	$I_C = 10mA$	I <sub>B</sub> = 1mA			0.8	V
		$I_C = 50mA$	I <sub>B</sub> = 5mA			0.9	
		I <sub>C</sub> = 150mA	I <sub>B</sub> = 15mA			1.2	
	SMALL SIGNAL CHARACTERIST	ics					
f <sub>T</sub>	Current-Gain–Bandwidth Product <sup>2</sup>	V <sub>CE</sub> = 20V	$I_C = 20mA$ f = 100MHz	150			MHz
C <sub>obo</sub>	Output Capacitance	V <sub>CB</sub> = 10V	I <sub>E</sub> = 0 f = 1MHz			8	
C <sub>ibo</sub>	Input Capacitance	V <sub>EB</sub> = 0.5V	I <sub>C</sub> = 0			80	pF
Olbo	mpat Capacitance		f = 1MHz				
h <sub>ie</sub>	Input Impedance	V <sub>CE</sub> = 10V	I <sub>C</sub> = 10mA f = 1KHz	0.25		1.25	Ω
h <sub>re</sub>	Voltage Feedback Ratio	V <sub>CE</sub> = 10V	$I_C = 10mA$ f = 1KHz			4	x10 <sup>-4</sup>
h <sub>fe</sub>	Small-Signal Current Gain	V <sub>CE</sub> = 10V	$I_C = 10mA$ f = 1KHz			375	_
h <sub>oe</sub>	Output Admittance	V <sub>CE</sub> = 10V	$I_C = 10mA$ f = 1KHz			200	Ω

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

**Semelab plc.** Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

E-mail: sales@semelab.co.uk

Website: http://www.semelab.co.uk

Document Number 5974





# **ELECTRICAL CHARACTERISTICS Continued** (T<sub>A</sub> = 25°C unless otherwise stated)

	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
	SWITCHING CHARACTERISTICS					
t <sub>d</sub>	Delay Time	$I_C = 150 \text{mA}$ $I_{B1} = 15 \text{mA}$ $V_{CC} = 100 \text{V}$ $V_{EB(off)} = -2 \text{V}$		20		ns
t <sub>r</sub>	Rise Time	$I_{C} = 150 \text{mA}$ $I_{B1} = 15 \text{mA}$ $V_{CC} = 100 \text{V}$ $V_{EB(off)} = -2 \text{V}$		35		ns
t <sub>s</sub>	Storage Time	$I_C = 150 \text{mA}$ $V_{CC} = 100 \text{V}$ $I_{B1} = I_{B2} = 15 \text{mA}$		800		ns
t <sub>f</sub>	Fall Time	$I_C = 150 \text{mA}$ $V_{CC} = 100 \text{V}$ $I_{B1} = I_{B2} = 15 \text{mA}$		80		ns

- 1) Pulse test : Pulse Width <  $300\mu s$  ,Duty Cycle < 2%
- 2)  $f_t$  is defined as the frequency at which  $|h_{fe}|.f_{test}$

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612. Document Number 5974

E-mail: <a href="mailto:sales@semelab.co.uk">sales@semelab.co.uk</a> Website: <a href="http://www.semelab.co.uk">http://www.semelab.co.uk</a> Issue 1